BYV29F-600 Enhanced ultrafast power diode Rev. 02 — 7 March 2011



Product data sheet

Product profile 1.

1.1 General description

Enhanced ultrafast power diode in a SOD59 (2-lead TO-220AC) plastic package.

1.2 Features and benefits

- High thermal cycling performance
- Low on-state losses

- Low thermal resistance
- Soft recovery characteristic

1.3 Applications

■ Dual Mode (DCM and CCM) PFC

■ Power Factor Correction (PFC) for Interleaved Topology

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	-	600	V
I _{F(AV)}	average forward current	square-wave pulse; δ = 0.5; $T_{mb} \le 115$ °C; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	-	9	Α
Static chara	acteristics					
V _F	forward voltage	$I_F = 8 \text{ A}; T_j = 25 \text{ °C};$ see <u>Figure 5</u>	-	1.45	1.9	V
		I _F = 8 A; T _j = 150 °C; see <u>Figure 5</u>	-	1.25	1.7	V
Dynamic cl	naracteristics					
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 100 \text{ A/}\mu\text{s}$; $T_j = 25 \text{ °C}$; see Figure 6	-	17.5	35	ns



2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		, 14
2	Α	anode	mb	K — A 001aaa020
mb	mb	mounting base; cathode		
			0	
			SOD59 (TO-220AC)	

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BYV29F-600	TO-220AC	plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC	SOD59

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	600	V
V_{RWM}	crest working reverse voltage		-	600	V
V_R	reverse voltage	DC	-	600	V
I _{F(AV)}	average forward current	square-wave pulse; $\delta = 0.5$; $T_{mb} \le 115$ °C; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	9	Α
I _{FRM}	repetitive peak forward current	square-wave pulse; δ = 0.5 ; t_p = 25 μ s; $T_{mb} \le$ 115 °C	-	18	Α
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; sine-wave pulse; $T_{j(init)}$ = 25 °C; see Figure 3	-	91	Α
		t_p = 8.3 ms; sine-wave pulse; $T_{j(init)}$ = 25 °C; see Figure 3	-	100	Α
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C

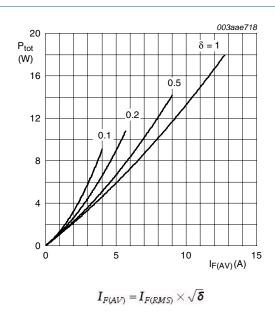
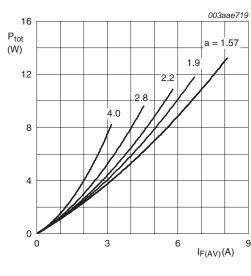


Fig 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a =form factor $= I_{F(RMS)} / I_{F(AV)}$

Fig 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

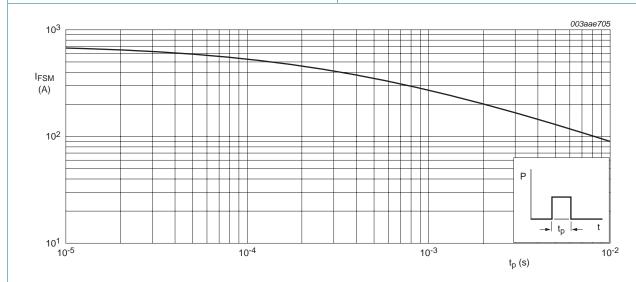


Fig 3. Non-repetitive peak forward current as a function of pulse width; square waveform; maximum values

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	see Figure 4	-	-	2.5	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	60	-	K/W

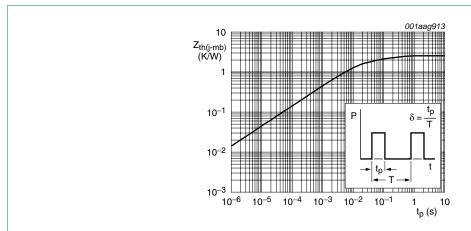
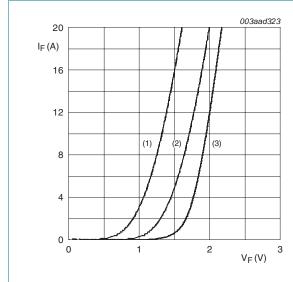


Fig 4. Transient thermal impedance from junction to mounting base as a function of pulse width

6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
Static chara	Static characteristics						
V _F	forward voltage	I _F = 8 A; T _j = 25 °C; see <u>Figure 5</u>	-	1.45	1.9	V	
		I _F = 8 A; T _j = 150 °C; see <u>Figure 5</u>	-	1.25	1.7	V	
I _R	reverse current	$V_R = 600 \text{ V}; T_j = 100 ^{\circ}\text{C}$	-	-	1.5	mA	
		$V_R = 600 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-	50	μΑ	
Dynamic ch	Dynamic characteristics						
Q _r	recovered charge	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 100 \text{ A/}\mu\text{s}$; see Figure 6	-	13	-	nC	
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 100 \text{ A/}\mu\text{s}$; $T_j = 25 \text{ °C}$; see Figure 6	-	17.5	35	ns	
I _{RM}	peak reverse recovery current	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 100 \text{ A/}\mu\text{s}$; see Figure 6	-	1.5	-	Α	
V _{FR}	forward recovery voltage	$I_F = 1 \text{ A}$; $dI_F/dt = 100 \text{ A/}\mu\text{s}$; see Figure 7	-	3.2	-	V	



(1) $T_j = 150 \, ^{\circ}C$; typical values (2) $T_j = 150 \, ^{\circ}C$; maximum values

(3) $T_j = 25$ °C; maximum values

Fig 5. Forward current as a function of forward voltage

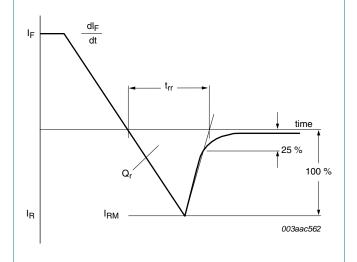
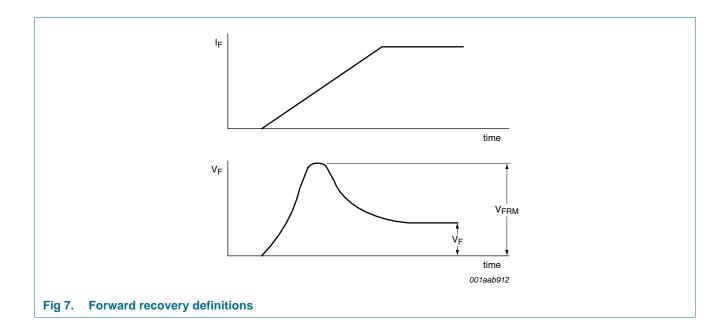


Fig 6. Reverse recovery definitions; ramp recovery



7. Package outline

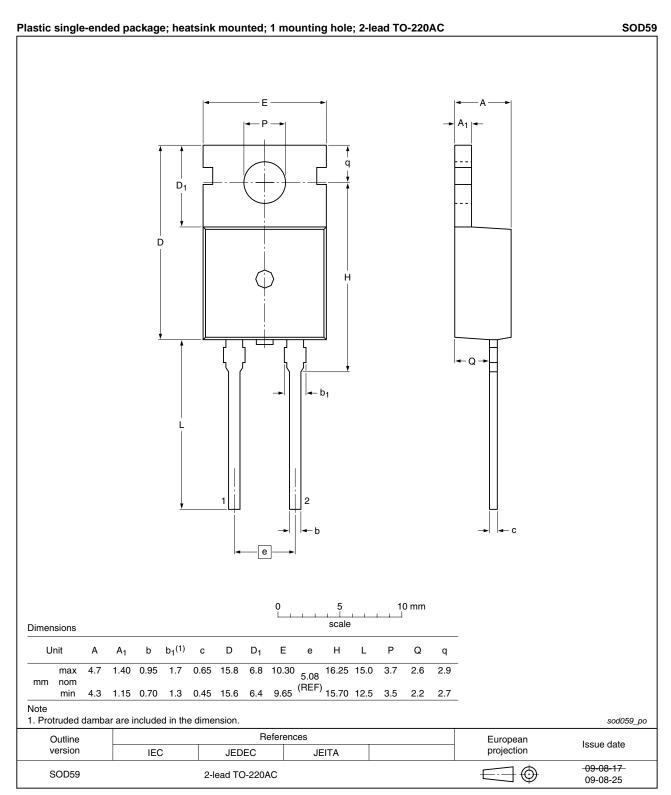


Fig 8. Package outline SOD59 (TO-220AC)



8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BYV29F-600 v.2	20110307	Product data sheet	-	BYV29F-600 v.1
Modifications:	 Various chang 	es to content.		
BYV29F-600 v.1	20100907	Product data sheet	-	-

9. Legal information

9.1 Data sheet status

Document status [1] [2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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